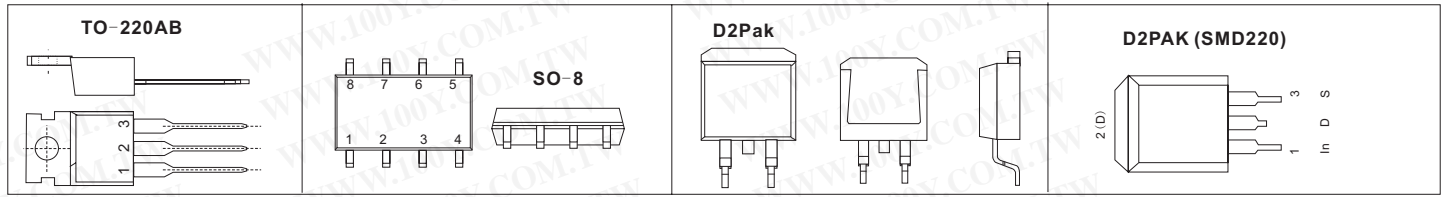




## IR~系列功率场效电晶体

详细产品规格 - 请点击 [cn.100y.com.tw](http://cn.100y.com.tw)



100Y 编号	厂商编号	制造厂商	说明	N/P Ch.	Pin/Package	Id(max.) A	Rds(on)(max.) Ω	Pd(max.) W	Vdss(max.) V
6078	IRF640NPBF	IR	TrenchMOS(tm) transistor	N-Ch.	3P/TO-220AB	18A	0.18Ω	125W	200V
33917	IRF640NSPBF	IR	HEXFET Power MOSFET	N	D2Pak	18A	0.15Ω	150W	200V
19611	IRF640S	IR	Surface Mount HEXFETR Power MOSFET	N-Ch	TO-263(D2Pak)	18A	0.18	130	200V
33918	IRF644	IR	Power MOSFET	N	TO-220AB	14A	0.28Ω	125W	250V
33919	IRF644S	IR	Power MOSFET	N	SMD-220	14A	0.28Ω	125W	250V
33923	IRF710	IR	Power MOSFET	N	TO-220AB	2.0A	3.6Ω	36W	400V
33924	IRF7101	IR	HEXFET Power MOSFET	N	SO-8	3.5A	0.16Ω	2.0W	20V
31704	IRF7103	IR	HEXFET Power MOSFET	N Ch.	SOP-8	3.0A	0.13	2.0W	50V
33925	IRF7104	IR	HEXFET Power MOSFET	P	SO-8	-2.3A	0.250Ω	2.0W	-20V
33926	IRF7105	IR	Power MOSFET	N and P Ch	SO-8	3.5A N-Ch/-2.3A P-Ch	0.10Ω N-Ch/0.25Ω P-Ch	2.0W	25V N-Ch/-25V P-Ch
6079	IRF712	HARRIS	TRANSISTOR	N-Ch.	3P/TO-220AB	1.7A	5Ω	36W	400V
33929	IRF720	IR	Power MOSFET	N	TO-220AB	3.3A	1.8Ω	50W	400V
33930	IRF7201	IR	Power MOSFET	N-Ch.	SO-8	7.3A	0.030Ω	2.5W	30V
23947	IRF7201D	IR	Power MOSFET	N-Ch.	8P/SOIC	7.3A	0.030Ω	2.5W	30V
33931	IRF7204	IR	HEXFET Power MOSFET	P	SO-8	-5.3A	0.060Ω	2.5W	-20V
33932	IRF7205	IR	HEXFET Power MOSFET	P	SO-8	-4.6A	0.070Ω	2.5W	-30V
33934	IRF7207	IR	HEXFET Power MOSFET	P	SO-8	-5.4A	0.06Ω	2.5W	-20V
33936	IRF7220	IR	HEXFET Power MOSFET	P	SO-8	11A	0.012Ω	2.5W	-14V
6080	IRF730	ST(SGS)	400V N-Channel MOSFET	N-Ch.	3P/TO-220AB	5.5A	1Ω	74W	400V
16068	IRF7301PBF	IR	Power MOSFET	N-Ch.	8P/SOIC	4.3A	0.05Ω	2W	20V
33938	IRF7303	IR	HEXFET Power MOSFET	N	SO-8	5.3A	0.050Ω	2.0W	30V
33940	IRF7304	IR	HEXFET Power MOSFET	P	SO-8	-4.7A	0.090Ω	2.0W	-20V
33943	IRF7306	IR	HEXFET Power MOSFET	P	SO-8	-4.0A	0.10Ω	2.0W	-30V
33945	IRF7307	IR	HEXFET Power MOSFET	N and P Channel	SO-8	5.7A N-Ch/-4.7A P-Ch	0.050Ω N-Ch/0.090Ω P-Ch	2.0W	20V N-Ch/-20V P-Ch
33947	IRF7309	IR	HEXFET Power MOSFET	N and P Channel	SO-8	4.7A N-Ch/-3.5A P-Ch	0.050Ω N-Ch/0.10Ω P-Ch	1.4W	30V N-Ch/-30V P-Ch
33948	IRF730A	IR	HEXFET Power MOSFET	N	TO-220AB	5.5A	1.0Ω	74W	400V
42164	IRF730PBF	IR	400V Single N-Channel HEXFET Power MOSFET	N-Ch.	3P/TO-220AB	5.5A	1Ω	74W	400V
19612	IRF730S	IR	Surface Mount Power MOSFET	N-Ch.	TO-263(D2Pak)	5.5A	1Ω	74W	400V
33958	IRF7311	IR	HEXFET Power MOSFET	N	SO-8	6.6A	0.029Ω	2.0W	20V
23758	IRF7313	IR	Power MOSFET	N-Ch.	8P/SOIC	6.5A	0.029Ω	2.0W	30V
33960	IRF7314	IR	HEXFET Power MOSFET	P	SO-8	-5.3A	0.058Ω	2.0W	-20V
16066	IRF7316	IR	Power MOSFET	P-Ch.	8P/SOIC	4.9A	0.058Ω	2W	30V
33961	IRF7317	IR	HEXFET Power MOSFET	N and P Channel	SO-8	6.6A N-Ch/-5.3A P-Ch	0.029Ω N-Ch/0.058Ω P-Ch	2.0W	20V N-Ch/-20V P-Ch
33962	IRF7319	IR	HEXFET Power MOSFET	N and P Channel	SO-8	6.5A N-Ch/-4.9A P-Ch	0.029Ω N-Ch/0.058Ω P-Ch	2.0W	30V N-Ch/-30V P-Ch
33963	IRF7324	IR	HEXFET Power MOSFET	P	SO-8	-9.0A	0.018 Ω	2.0W	-20V
33964	IRF7341	IR	HEXFET Power MOSFET	N	SO-8	4.7A	0.050Ω	2.0W	55V
33966	IRF7342	IR	HEXFET Power MOSFET	P	SO-8	-3.4A	0.105Ω	2.0W	-55V
33967	IRF7343	IR	HEXFET Power MOSFET	N and P Channel	SO-8	4.7A N-Ch/-3.4A P-Ch	0.050Ω N-Ch/0.105Ω P-Ch	2.0W	55V N-Ch/-55V P-Ch
33968	IRF7389	IR	HEXFET Power MOSFET	N and P Channel	SO-8	7.3A N-Ch/-5.3A P-Ch	0.029Ω N-Ch/0.058Ω P-Ch	2.5W	30V N-Ch/-30V P-Ch
33068	IRF7401PBF	IR	Power MOSFET	N-Ch.	8P/SOIC	8.7A	0.022		20V
42812	IRF7402PBF	IR	HEXFET POWER MOSFET	N-Ch.	SO-8	6.8A	35mΩ	2.5W	20V
23747	IRF7403PBF	IR	Power MOSFET	N-Ch.	8P/SOIC	8.5A	0.022	2.5W	30V
16067	IRF7404PBF	IR	Power MOSFET 无铅	P-Ch.	8P/SOIC	5.3A	0.040Ω	2.5W	-20V
28049	IRF7406PBF	IR	Power MOSFET	P-Ch.	8P/SO		0.045		-30V
33969	IRF740A	IR	HEXFET Power MOSFET	N	TO-220AB	10A	0.55Ω	125W	400V
33970	IRF740LC	IR	Power MOSFET	N	TO-220AB	10A	0.55Ω	125W	400V
6081	IRF740PBF	IR	MOSFET	N-Ch.	3P/TO-220AB	10A	0.55Ω	125W	400V

